

320A, 100V N-CHANNEL MOSFET

DESCRIPTION

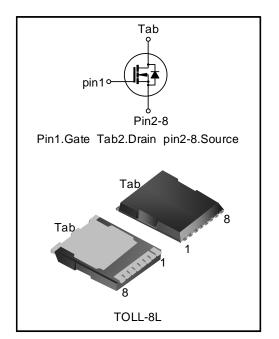
SVGP101R5NL is an N-channel enhancement mode power MOS field effect transistor which is produced using Silan's LVMOS technology. The improved process and cell structure have been especially tailored to minimize on-state resistance, provide superior switching performance.

This device is widely used in power management for UPS and Inverter Systems.

FEATURES

- 320A, 100V, $R_{DS(on)(typ.)}=1.1m\Omega@V_{GS}=10V$
- Low gate charge
- Low Crss
- Fast switching
- Extreme dv/dt rated
- 100% avalanche tested
- Pb-free lead plating
- RoHS compliant

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KEY PERFORMANCE PARAMETERS

Characteristics	Ratings	Unit
V _{DS}	100	V
V _{GS(th)}	2.2~3.8	V
R _{DS(on),max}	1.5	mΩ
I _D	320	A
Q _{g.typ}	238	nC

ORDERING INFORMATION

Part No.	Package	Marking	Hazardous Substance Control	Packing Type
SVGP101R5NLTR	TOLL-8L	P101R5N	Halogen free	Tape&reel

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ABSOLUTE MAXIMUM RATINGS (UNLESS OTHERWISE NOTED, TJ=25°C)

Characteristics	Cumbal	mbol Test conditions	Ratings			l lucit
Characteristics	Symbol	rest conditions	Min.	Min. Typ. Max.	Max.	Unit
Drain-source Voltage	V_{DS}				100	V
Gate-source Voltage	V_{GS}		-20		20	V
Drain Current (Note 1)		T _C =25°C			320	Α
Drain Current (Note 1)	Ι _D	T _C =100°C			210	Α
Drain Current Pulsed (Note 2)	I _{DM}	T _C =25°C			1280	Α
Power Dissipation (Note 3)	P_D	T _C =25°C			321	W
Single Pulsed Avalanche	_	L=0.1mH, V_{DD} =80V, R_{G} =25 Ω ,			756	mJ
Energy	E _{AS}	starting temperature T _J =25°C				
Single Pulsed Avalanche	1				123	А
Current	IAS	I _{AS}				
Operation Junction	т.	T 55	-55	55	150	°C
Temperature Range	ТJ		-55		130	
Storage Temperature Range	T _{stg}		-55		150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Symbol Test conditions	Ratings			Unit
	Test conditions	Min.	Тур.	Max.	Offic	
Thermal Resistance,	В				0.39	°C/W
Junction-case, Bottom	$R_{\theta JC}$				0.39	C/VV
Thermal Resistance,	$R_{\theta JA}$	R _{0JA}			45	0000
Junction-ambient					45	°C/W
Soldering Temperature	T _{sold}	T _{sold} Reflow soldering: 10 ± 1 sec, 3 times			260	°C
(SMD)	I sold	Reliow soldering. 10 ± 1 sec, stiffles			200	J

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ELECTRICAL CHARACTERISTICS (UNLESS OTHERWISE NOTED, TJ=25°C)

Static characteristics

Characteristics	Symbol	Test conditions	Ratings			Unit
Onaracteristics		rest conditions	Min.	Тур.	Max.	Offic
Drain-source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	100			V
Drain-source Leakage Current	1	V _{DS} =100V, V _{GS} =0V, T _J =25°C			1.0	μA
Drain-source Leakage Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V, T _J =125°C		9.0		μA
Gate-source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}$, $I_{D}=250\mu A$	2.2		3.8	V
Static Drain-source	D _{no} ,	V _{GS} =10V, I _D =150A		1.1	1.5	mΩ
On State Resistance	$R_{DS(on)}$	V _{GS} =6.0V, I _D =75A		1.4	2.0	mΩ
Gate Resistance	R_g	f=1MHz		2.8		Ω

Dynamic characteristics

	Comple ed	Took conditions	Rati		Ratings	
Characteristics	Symbol Test conditions	Min.	Тур.	Max.	Unit	
Input Capacitance	C _{iss}			17694		
Output Capacitance	Coss	f=1MHz, V _{GS} =0V, V _{DS} =50V		2681		pF
Reverse Transfer Capacitance	C _{rss}			66		
Turn-on Delay Time	t _{d(on)}	V 50V V 40V B 400		47		
Turn-on Rise Time	t _r	V_{DD} =50V, V_{GS} =10V, R_{G} =1.8 Ω ,		85		
Turn-off Delay Time	t _{d(off)}	I _D =100A (Notes 4.5)		139		ns
Turn-off Fall Time	t _f	(Notes 4,5)		78		
Total Gate Charge	Q_g			239		
Gate-source Charge	Q _{gs}	V _{DD} =50V, V _{GS} =10V, I _D =100A		85		nC
Gate-drain Charge	Q_{gd}	(Notes 4,5)		40		
Gate-plateau Voltage	V _{plateau}			4.9		V

Reverse diode characteristics

Characteristics	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Continuous Source Current	Is	Integral Reverse P-N Junction			320	А
Diode pulse current	I _{S,pulse}	Diode in the MOSFET			1280	A
Diode Forward Voltage	V_{SD}	I _S =100A, V _{GS} =0V			1.4	٧
Reverse Recovery Time	Trr	I _S =100A, V _{GS} =0V, V _R =80V		111		ns
Reverse Recovery Charge	Q_{rr}	dI _F /dt=100A/μs (Note 4)		299		nC

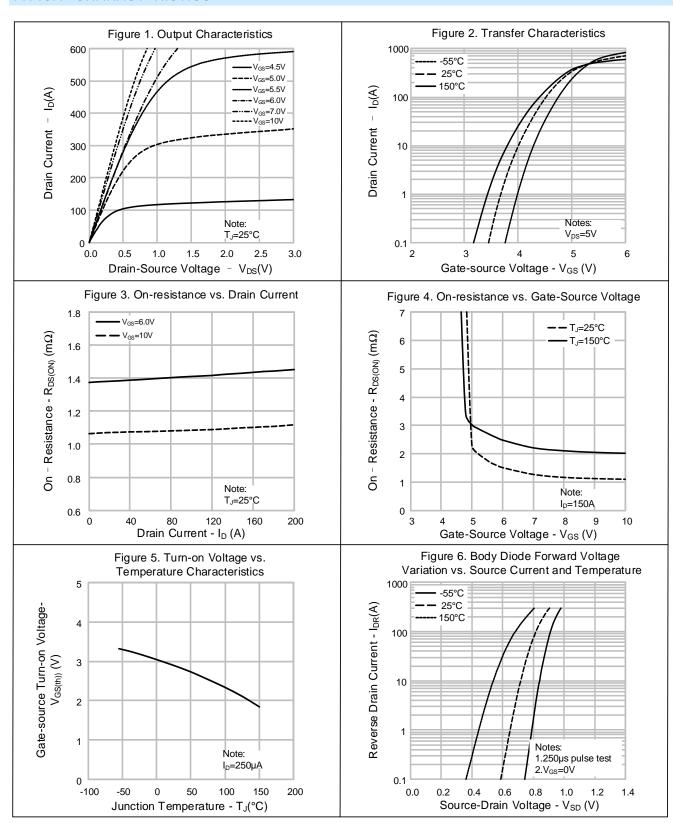
Notes:

- 1. The rated value only refers to the maximum absolute value at the case temperature of 25°C in the specification. If the case temperature is higher than 25°C, it should be derated according to the actual environmental conditions;
- 2. Pulse time 5µs;
- The dissipation power will change with temperature, derating above 25°C: 2.56W/°C; 3.
- Pulse Test: Pulse width ≤300µs, Duty cycle≤2%; 4.
- Essentially independent of operating temperature.

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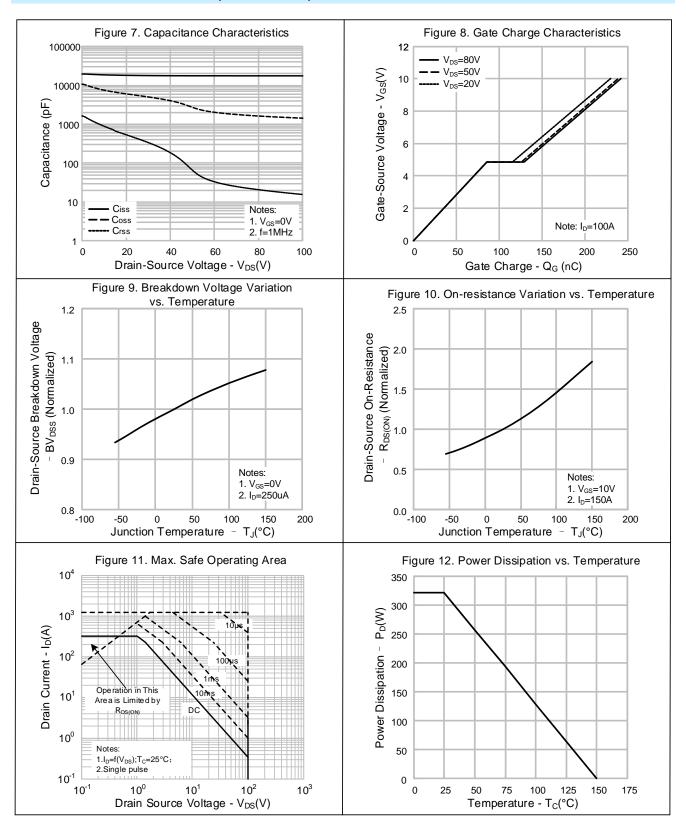
TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS (CONTINUED)

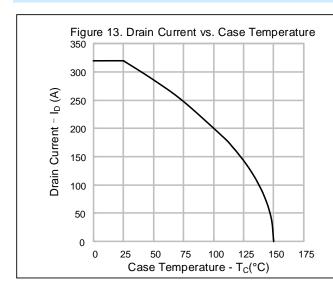


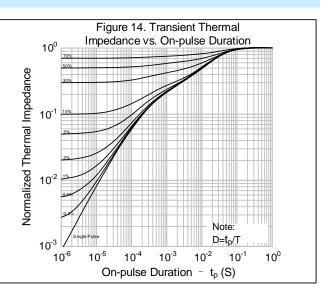
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TYPICAL CHARACTERISTICS (CONTINUED)



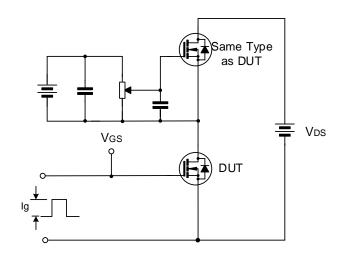


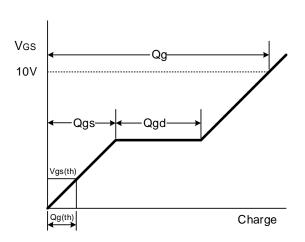
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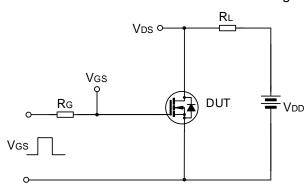
TYPICAL TEST CIRCUIT

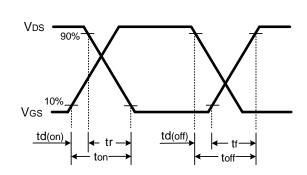
Gate Charge Test Circuit & Waveform



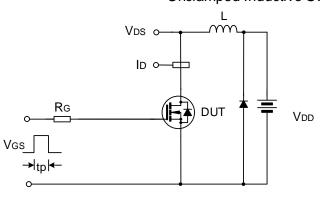


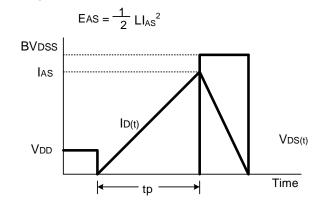
Resistive Switching Test Circuit & Waveform





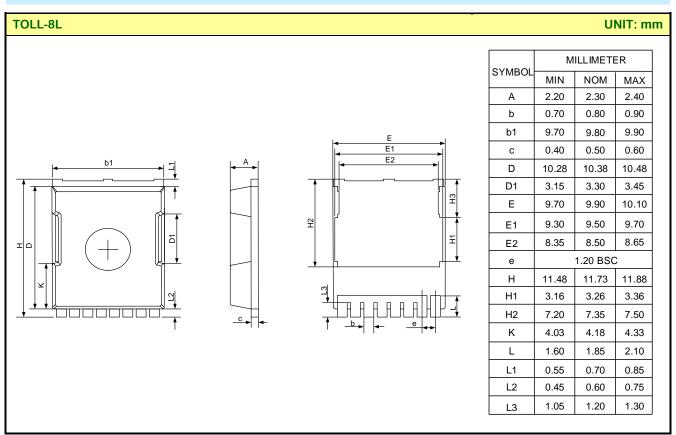
Unclamped Inductive Switching Test Circuit & Waveform







PACKAGE OUTLINE





MOS DEVICES OPERATE NOTES:

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.



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Important notice:

- 1. Silan reserves the right to make changes of this instruction without notice.
- 2. Customers should obtain the latest relevant information when purchasing and should verify whether such information is latest and complete. Please read this instruction and application manual and related materials carefully before using products, including the circuit operation precautions, etc.
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- Please use and apply product in compliance with all applicable laws and regulations, including but not limited to trade control regulations etc. The product is civil electronic product, please do not use it in non-civil fields.
- 8. Product promotion is endless, our company will wholeheartedly provide customers with better products!
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First release

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